NSN 5961-01-023-2829

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Inclosure Material:

Plastic

Overall Length:

0.643 inches

Overall Height:

0.135 inches

Overall Width:

0.505 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown

voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

90.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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